
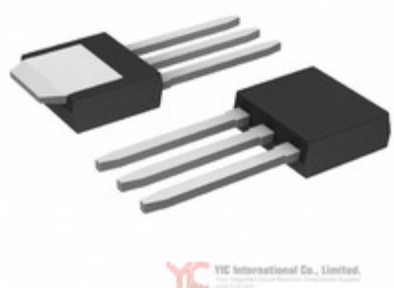








	<h2 style="color: red;">NTD4815N-1G</h2>
	<p>Hersteller-Teilenummer: NTD4815N-1G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 6.9A IPAK</p> <p>Datenblätter:  NTD4815N-1G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 8239 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTD4815N-1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 30V 6.9A IPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	8239 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Stub Leads, IPak
Supplier Device-Gehäuse	I-Pak
Verlustleistung (max)	1.26W (Ta), 32.6W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	6.9A (Ta), 35A (Tc)
Rds On (Max) @ Id, Vgs	15 mOhm @ 30A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	6.6nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	770pF @ 12V
Verpackung	Tube



















































NTD4815N-1G ist neu im Original, Suche NTD4815N-1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD4815N-1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD4815N-1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTD4813NT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 7.6A DPAK</p>	 <p>NTD4815N-35G AMI Semiconductor / ON Semiconductor MOSFET NCH 30V 6.9A IPAK TRIMMED</p>	 <p>NTD4813NHG ON/ NTD4813NHG ON/</p>	 <p>NTD4815NH-35G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 6.9A IPAK</p>
 <p>NTD4815 AMI Semiconductor / ON Semiconductor NTD4815 ON</p>	 <p>NTD4815NH AMI Semiconductor / ON Semiconductor NTD4815NH ON</p>	 <p>NTD4815N ON NTD4815N ON</p>	 <p>NTD4815NH-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 6.9A IPAK</p>

heiße Teile

Mehr

 NTD4806NG	 NTD4806NT4G	 NTD4808N	 NTD4808N-35G	 NTD4808NG
 NTD4808NT4G	 NTD4809N-35G	 NTD4809NAT4G	 NTD4809NH-35G	 NTD4809NHG
 NTD4809NHT4G	 NTD4809NT4G	 NTD4810N	 NTD4810N-1G	 NTD4810N-35G
 NTD4810NHT4G	 NTD4810NT4G	 NTD4813N	 NTD4813N-1G	 NTD4813NH-1G
 NTD4813NH-35G	 NTD4813NHG	 NTD4813NHT4G	 NTD4813NT4G	 NTD4815N
 NTD4815NHT4G	 NTD4815NT4G	 NTD4854NT4G	 NTD4855N	 NTD4855NT4G
 NTD4856NG	 NTD4856NT4G	 NTD4857NAT4G	 NTD4857NT4G	 NTD4858N
 NTD4858NAT4G	 NTD4858NT4G	 NTD4860N	 NTD4860NA-1G	 NTD4860NAT4G
 NTD4860NT4G	 NTD4863N	 NTD4863NAT4G	 NTD4863NT4G	 NTD4865N
 NTD4904N	 NTD4904N-1G	 NTD4904N-35G	 NTD4904NT4G	 NTD4905NT4G

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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